

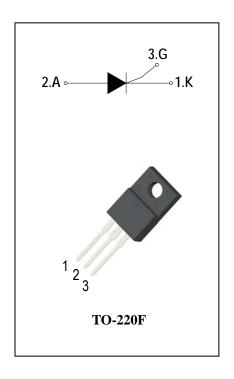
SCRs

General Description

The 40A SCR series of silicon controlled rectifiers, with high ability to withstand the shock loading of large current, provide high dv/dt rate with strong resistance to electromagnetic interference. They are especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc.

Features

- ◆ Repetitive Peak Off-State Voltage: 1000V and 1200V
- ◆ R.M.S On-State Current (IT(RMS)= 40 A)
- ♦ These are Pb-Free Devices



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit				
V_{DRM}	Repetitive Peak Off-State Voltage	Ti=25°C	ADS40A100F	1000	V				
V_{RRM}	Repetitive peak reverse voltage	Tj=25°C	ADS40A120F	1200	V				
I _{T(AV)}	Average On-State Current	Half Sine Wave , Tc = 85°C		25	Α				
I _{T(RMS)}	R.M.S On-State Current	Half Sine Wave , Tc = 85°C		40	Α				
I _{TSM}	Surge On-State Current	1/2 Cycle, Sine Wave Non-Repetitive, tp=10ms(50Hz)Tj =25°C		460	Α				
I ² t	I ² t for Fusing	Tj =25°C,tp =10ms		1060	A^2S				
P _{GM}	Forward Peak Gate Power Dissipation	Tj =125°C, Pulse Width ≤ 20μs		5	W				
$P_{G(AV)}$	Forward Average Gate Power Dissipation	Tj =25°C, tp =10ms		1	W				
I _{GM}	Peak Gate Current	Tj =125°C, Pulse Width $\leq 20 \mu s$		4	А				
Tj	Operating Junction Temperature			- 40 ~ 125	°C				
T_{STG}	Storage Temperature			_				- 40 ~ 150	°C





ADS40A100F/120F

Electrical Characteristics (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS40A100F/120F		Unit
				S	Blank	7
		$V_{DRM} = V_{RRM}$		1	0	uA
I _{DRM}	Peak Forward Reverse	Tj = 25°C	Max.	10		
I _{RRM}	Blocking Current	$V_{DRM} = V_{RRM}$ $Tj = 125^{\circ}C$	IVIAX.	4		mA
V _{TM}	Peak On-State Voltage	I _{TM} = 80A, t _p = 380 μs	Max.	1.6		V
V_{GD}	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 125^{\circ}\text{C}$	Min.	0.2		V
V_{GT}	Gate Trigger Voltage	V 40V B 000	Max.	1.3		V
I _{GT}	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	15	30	mA
I _H	Holding Current	I _T = 0.5A	Max.	30	40	mA
ΙL	Latching Current	I _G = 1.2 I _{GT}	Max.	50	50	mA
dV/dt	Critical Rate of Rise of Off-State Voltage	$V_D = 2/3V_{DRM}$ gate open $Tj = 125^{\circ}C$	Min.	1000	1500	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	1.0		°C/W
R _{th(j-a)}	Junction to ambient		Max.	60		°C/W

FIG.1: Maximum average power dissipation (Single phase half wave)

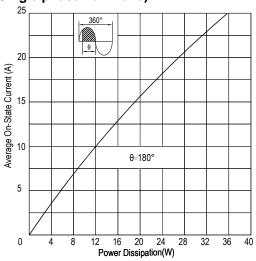


FIG.3: Gate trigger current VS Junction temperature

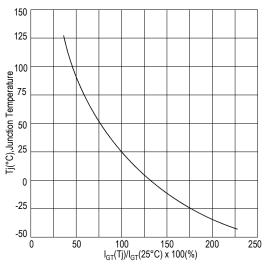


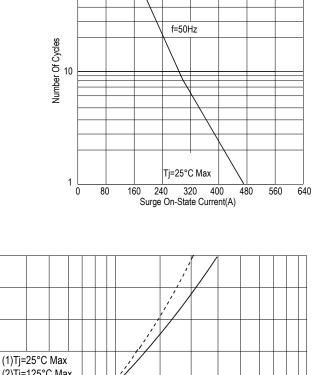
FIG.5: On-state characteristics(Max)

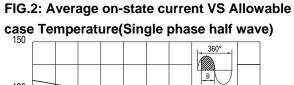
3.5

V_{TM}(V),On-State Voltage

1

0.5^L





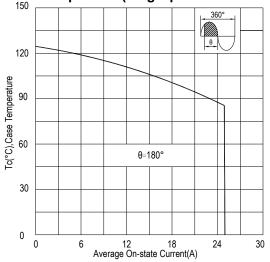
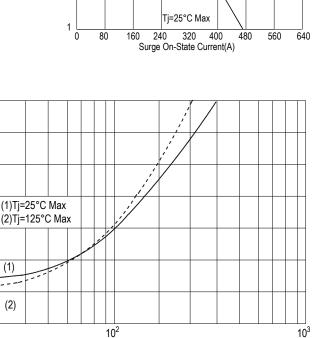


FIG.4: Rated surge on-state current (Non-Repetitive)



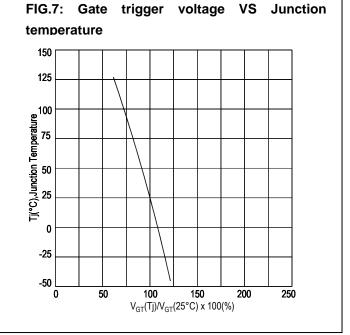
(1)

(2)

10¹



ADS40A100F/120F

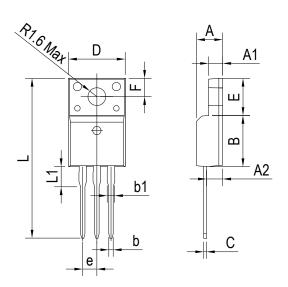


4 / 6 www.advsemi.com Feb,2013 -Rev.3.01



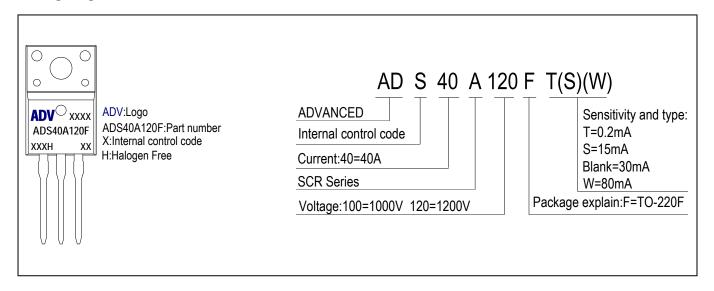
PACKAGE MECHANICAL DATA

TO-220F Package Dimension



	Dimensions In		Dimensions In		
Symbol	Millimeters		Inches		
	Min	Max	Min	Max	
Α	4.300	4.800	0.169	0.189	
A1	2.400	2.700	0.094	0.106	
A2	2.500	3.000	0.098	0.118	
В	8.800	9.300	0.346	0.367	
b	0.600	0.950	0.023	0.037	
b1	1.100	1.700	0.043	0.067	
С	0.500	0.750	0.020	0.030	
D	9.700	10.360	0.382	0.408	
Е	6.400	6.800	0.252	0.268	
е	2.540 TYP		0.100 TYP		
F	3.300 REF		0.130 REF		
L	28.000	30.000	1.102	1.181	
L1	2.900	3.630	0.114	0.143	

Making Diagram



Ordering information

Part number	Package	Marking	Packing	Quantity		
ADS40A100F#	TO-220F	ADS40A100F#	Tube	50pcs		
ADS40A120F#	TO-220F	ADS40A120F#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADS40A100F/120F

Notice

- 1. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any ADV products listed in this document, please confirm the latest product information with a ADV sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by ADV such as that disclosed through our website. (http://www.advsemi.com)
- 2. ADV has used reasonable care in compiling the information included in this document, but ADV assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document.
- 3. You should use the products described herein within the range specified by ADV, especially with respective the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. ADV shall have no liability for malfunctions or damages arising out of the use of ADV products beyond such specified ranges.
- 4. When using or otherwise relying on the information in this document, you should evaluate the information in light of the total system before deciding about the applicability of such information to the intended application. ADV makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or ADV products.
- 5. Although ADV endeavors to improve the quality and reliability of its products, IC products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a ADV product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 6. This document is provided for reference purposes only so that ADV customers may select the appropriate ADV products for their use. ADV neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of ADV or any third party with respect to the information in this document.
- 7. ADV shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.
- 8. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written approval from ADV.

6 / 6 www.advsemi.com Feb,2013 -Rev.3.01